



SM2T3V3A

Low voltage Transil™

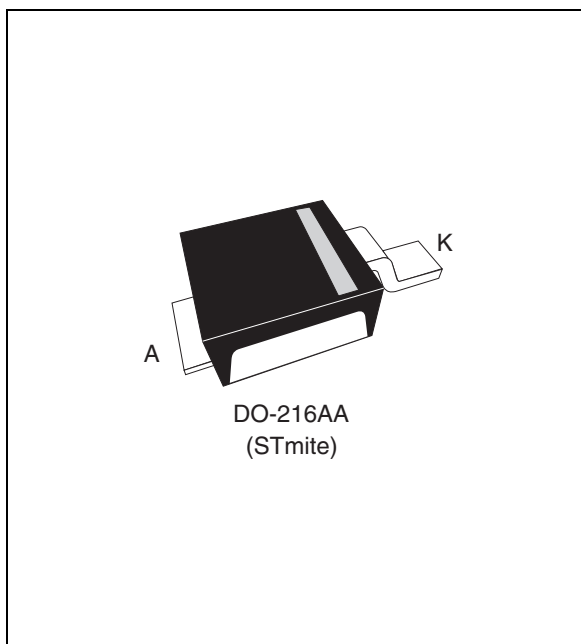
Features

- unidirectional Transil diode
- high peak pulse power: 200 w (10/1000 μ s)
- stand-off voltage 3.3 V
- low clamping factor V_{CL}/V_{BR}
- fast response time
- JEDEC registered package outline

Description

The SM2T3V3A is a Transil diode designed specifically for portable equipment and miniaturized electronic devices subject to ESD transient overvoltages. Its low stand-off voltage makes it suitable for low voltage applications very sensitive to EOS and ESD events.

Transil diodes provide high overvoltage protection by clamping action.



TM: Transil is a trademark of STMicroelectronics

1 Characteristics

Table 1. Absolute rating (limiting value)

Symbol	Parameter		Value	Unit
P _{PP}	Peak pulse power dissipation ⁽¹⁾	T _j initial = T _{amb}	200	W
P	Power dissipation on infinite heatsink	T _{amb} = 100°C	2.5	W
I _{FSM}	Non repetitive surge peak forward current	t _p = 10 ms T _j initial = T _{amb}	25	A
T _{stg} T _j	Storage temperature range Maximum operating junction temperature		-65 to +175 150	°C
T _l	Lead solder temperature (10 seconds duration)		260	°C

1. 10/1000 μs pulse waveform

Table 2. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-l)}	Junction to leads	20	°C/W
R _{th(j-a)}	Junction to ambient on PCB with recommended pad layout	250	°C/W

Table 3. Electrical characteristics - parameters (T_{amb} = 25 °C)

Symbol	Parameter
V _{RM}	Stand-off voltage.
V _{BR}	Breakdown voltage.
V _{CL}	Clamping voltage.
I _{RM}	Leakage current @ V _{RM} .
I _{PP}	Peak pulse current.
αT	Voltage temperature coefficient
V _F	Forward voltage drop

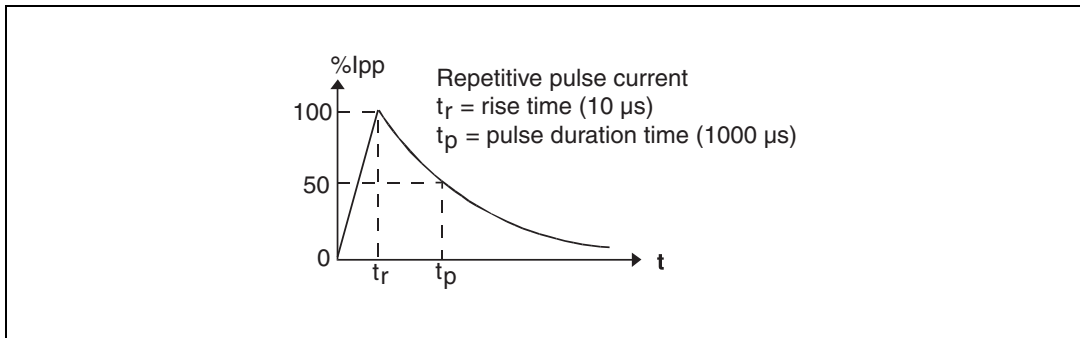
The graph shows the current-voltage (I-V) characteristics of the diode. The vertical axis is current (I) and the horizontal axis is voltage (V). In the reverse bias region (left side), the diode blocks current until the breakdown voltage V_{BR} is reached. At this point, the current increases sharply. The clamping voltage V_{CL} is indicated at the peak of the reverse current. The reverse leakage current I_{RM} is shown at the stand-off voltage V_{RM}. In the forward bias region (right side), the diode conducts current starting at the forward voltage drop V_F. The peak pulse current I_{PP} is shown at the peak of the forward current.

Table 4. Electrical characteristics - values (T_{amb} = 25 °C)

Order code	I _{RM} max @ V _{RM}		V _{BR} min @ I _R ⁽¹⁾		V _{CL} max @ I _{PP} 10/1000 μs		V _{CL} max @ I _{PP} 10/1000 μs		αT max ⁽²⁾	C max ⁽³⁾
	μA	V	V	mA	V	A	V	A	10 ⁻⁴ /°C	pF
SM2T3V3A	500	3.3	3.6	1	6.5	25	6.8	30	-5.3	2500

1. Pulse test t_p < 50 ms
2. ΔV_{BR} = αT * (T_{amb} - 25) + V_{BR} (25 °C)
3. V_R = 0 V, F = 1 MHz

Table 5. Pulse waveform



2 Package information

- epoxy meets ul94, v0
- band indicates cathode

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Figure 1. Package dimensions - parameters

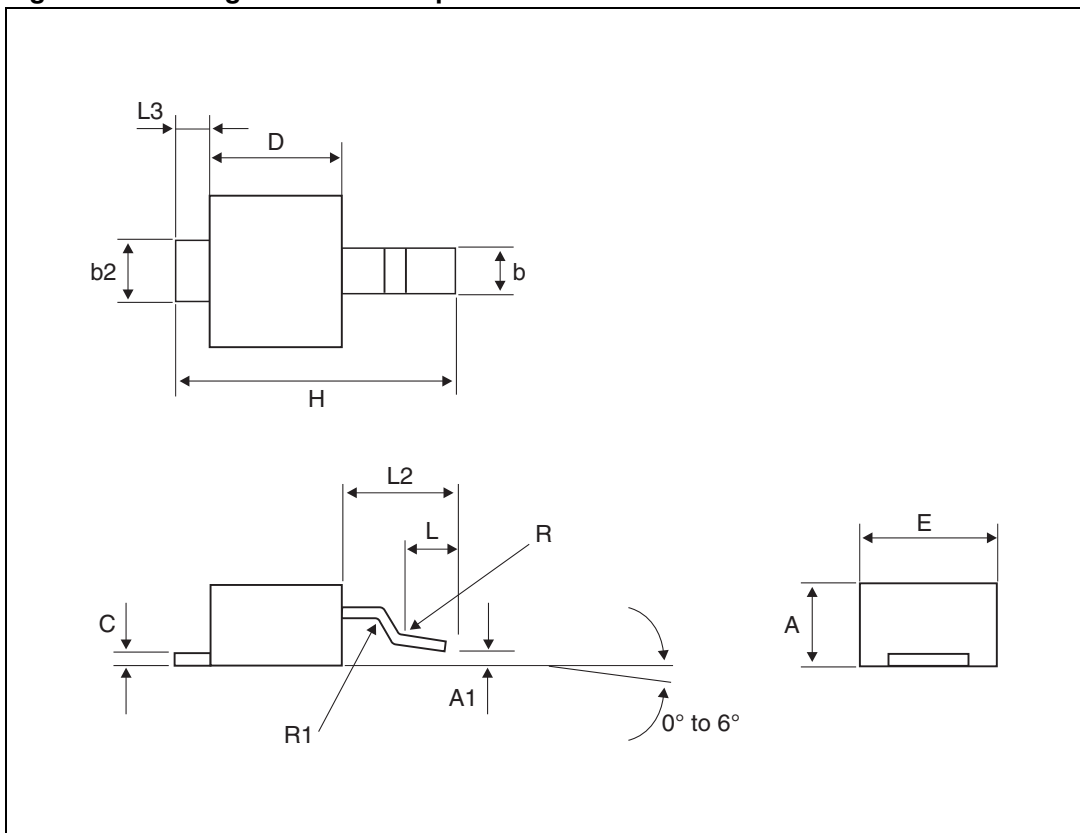
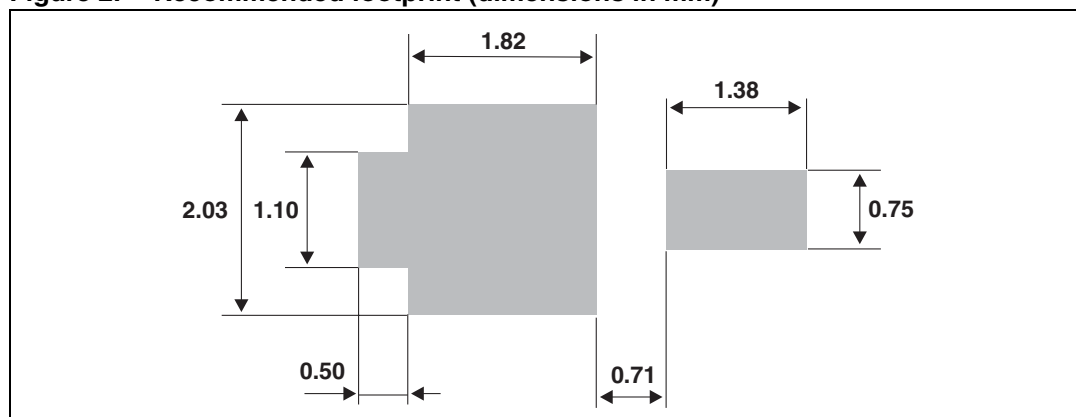


Table 6. Package dimensions - values

Ref.	Dimensions					
	Millimetres			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.85	1.00	1.15	0.033	0.039	0.045
A1	-0.05		0.105	-0.002		0.002
b	0.40		0.65	0.016		0.025
b2	0.70		1.00	0.027		0.039
c	0.10		0.25	0.004		0.010
D	1.75	1.90	2.05	0.069	0.007	0.081
E	1.75	1.90	2.05	0.069	0.007	0.081
H	3.60	3.75	3.90	0.142	0.148	0.154
L	0.50	0.63	0.80	0.047	0.025	0.031
L2	1.20	1.35	1.50	0.047	0.053	0.059
L3		0.50 ref			0.019 ref	
R	0.07			0.003		
R1	0.07			0.003		

Figure 2. Recommended footprint (dimensions in mm)



3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base quantity	Delivery mode
SM2T3V3A	MUL	STmite	15.5 mg	12000	Tape and reel

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
10-Oct-2005	1	First Issue
09-Dec-2010	2	Cathode band added to package illustration.

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